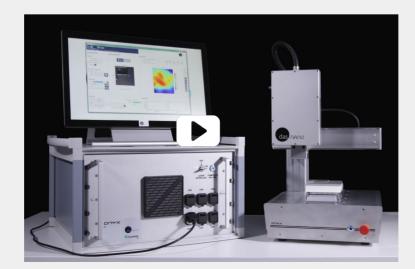


das-Nano Onyx

Terahertz research platform for bulk, thin films and 2D materials

das-Nano Onyx is the first system in the market designed to provide a full-area non-destructive characterization of electrical properties of bulk, thin films and 2D materials.

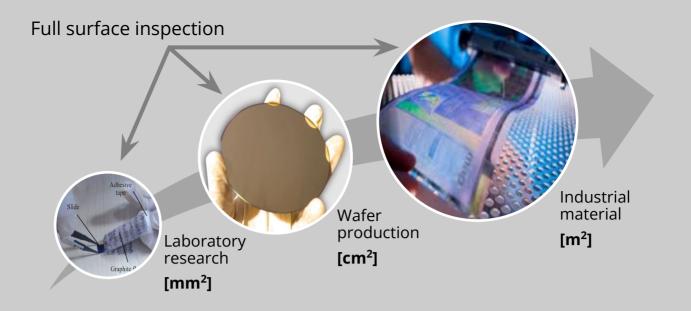


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www.das-nano.com info@das-nano.com





Improve and fully check your quality control process with das-Nano Onyx



Electrical parameters characterization system



Contactless and **non-destructive** Terahertz-based system

Full surface map and single point of electrical properties



Ultra-fast & **high resolution** characterization Up to 12 cm²/min & 50 μm



Wide range of materials Graphene, semiconductors, ITO, GaN, NbC, IZO, ZnO, PEDOT...

Direct benefits for your business



100% inspected production



Faster development of new materials



Knowledge of all of your material surface electrical quality



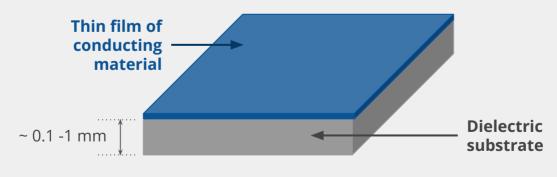
• Cost savings: early detection of production errors





MEASUREMENT CONFIGURATIONS

Thin films and bulk materials Conductive films under protective coatings 2D materials onto dielectric substrates: • 2D materials: graphene (mono- bi- and multilayer, inks, doped, Materials epitaxial over SiC, powder & flakes, graphene oxide), PEDOT, ITO, NbC, IZO, ALD-ZnO, GaN, spin coated photoresins... · Substrates: quartz, silica, sapphire, high/medium resistivity silicon, silicon carbide, polymers... Thickness: 0.1 -1 mm. Custom substrate characterization available. No upper sample size limit (> $1x1 \text{ cm}^2$) Sample geometry Flat samples Dry, wet and cured materials Wetness condition Kinetics research tool available Photovoltaics, graphene, semiconductors, electronics, batteries, Markets of interest advanced materials...



Scheme of a conductive 2D material onto a dielectric substrate

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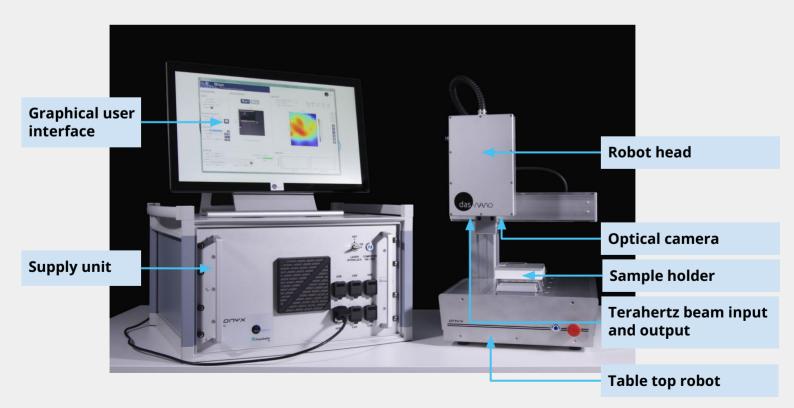
PERFORMANCE OF THE SYSTEM

Terahertz polarization	Linear		
Measurable parameters	Sheet conductance (0,1 - 40 mS) Sheet resistance (25 - 10,000 Ohm)		
	Carrier mobility Carrier density Carrier scattering time Refractive index Dielectric parameters, ε' and ε"	Absorbed power Single-frequency features Uniformity and homogeneity Time-domain terahertz waveforms Terahertz spectra	
Sampled area per point	3-mm terahertz spot size		
Robot resolution	Selectable from 50 µm		
Measurement time	Up to 50 ms/point Ultra fast: up to 12 cm²/min		
Mapping	Single point and full area inspection		
Measurement mode	Reflection Normal incidence (0°) Focused beam Single side inspection		
Measurement head distance to the inspected surface	Automatically adapted for every sample		
Measurement traceability	HD optical camera to ensure traceability		





Supply unit	610 x 581 x 332 mm (L x W x H), 46 kg
Terahertz head	176 x 67 x 260 mm (L x W x H), 2 kg
Actuator	Default: 401 x 535.5 x 546 mm (L x W x H), 27 kg, scanning area 200 x 200 mm. Plug and play system. Any conventional robot or cobot can be attached to das-Nano Onyx
Sample holder	Customizable shape and size
Reference samples	To check the correct functioning of the system:Quartz wafer (100 um thick)PEDOT onto 100 um thick quartz wafer
Software	 User-friendly graphical user interface Multiple selectable measurement and analysis parameters In-situ and subsequent analysis Temporal and spectral exportable results
Customizable	Available development support to adapt the product hardware and/or software to the end-user needs



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OPERATIONAL REQUIREMENTS

Robotic system	Compatible with any conventional robot: any model and brand
Operating temperature	15°C (59°F) – 35°C (95°F)
Operating humidity	Relative humidity < 75%
Operating atmosphere	Air, nitrogen, argon Vacuum Non-condensing atmosphere
Sample preparation	No sample preparation required
Calibration	Autorefentiated measurements, no calibrations required
Power requirements	110 / 240 VAC, 4 A-line power, 50-60 Hz Single phase, two-wire plug
Auxiliary systems	No auxiliary systems are required Nitrogen output available for measurements at low humidity
Quality certifications	CE marking, REACH and RoHS compliant, ISO 9001, ISO 27001
Safety considerations	Non-ionizing radiation: harmless to humans
International standards	Complies with IEC TS 62607-6-10:2021 Nanomanufacturing - Key control characteristics - Part 6-10: Graphene-based material - Sheet resistance: Terahertz time-domain spectroscopy

